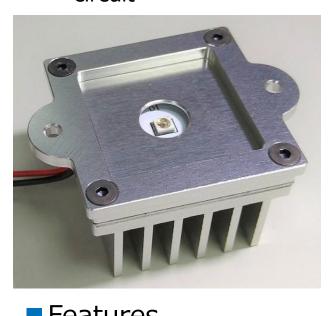


-Built-in GaN FET-UVC module

 Excellent sterilization with high power UVC LED (270nm, 50mW) Small and compact size UVC module with built-in GaN FET driving circuit



Advantages

- High output power : 50mW irradiation power
- **Built-in driving circuit :** 12V/350mA driver circuit included No additional circuit needed

NTT-ATO 5000212.

Compact size : Very low heat emission

Features		
LED spec. (@Vf=6~6.5V)		
Wavelength	260 ~ 280 nm	
Forward current	350 mA	
Power	50 mW	
Radiation angle	120 °	
Driving circuit spe	ec.	
Input voltage	12 V	Dimension (mm)
Forward current	350 mA	
Power consumption	4.2 W	
Heat dissipation	Tj≦100°C@Ta40°C, 350mA	
Operation temp.	0∼50 °C	
Module spec.		
Dimension	56 x 42 x 27 mm	
Application		

- Surface sterilization
- Purifier (Air, Water, etc.)

Manufactured by

GaN Power Technology Co., Ltd.

